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KIRIRI WOMENS' UNIVERSITY OF SCIENCE AND TECHNOLOGY
UNIVERSITY EXAMINATION, 2022/2023 ACADEMIC YEAR
SECOND YEAR, FIRST SEMESTER EXAMINATION
FOR THE DEGREE OF BACHELOR OF SCIENCE
(COMPUTER SCIENCE)

Date: 20th April, 2022
Time: 8.30am –10.30am

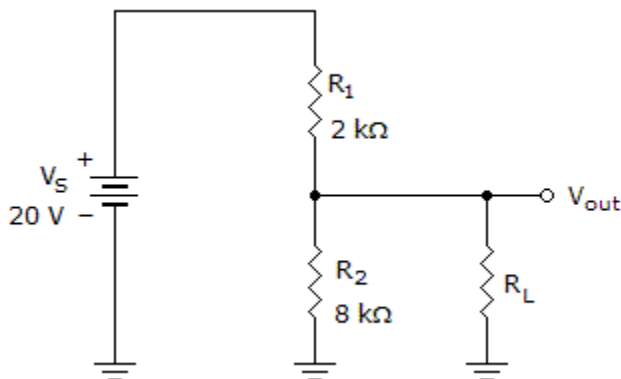
KCS 203 - ELECTRONICS

INSTRUCTIONS TO CANDIDATES

ANSWER QUESTION ONE (COMPULSORY) AND ANY OTHER TWO QUESTIONS

QUESTION ONE (30 MARKS)

- a) State ohm's law. (2 marks)
- b) Briefly describe the following terms giving the units of measurement used in each of them. (6 marks)
- i) Electric Charge
 - ii) Voltage
 - iii) Resistance
- c)



If the load (R_L) in the given circuit is $120\text{ k}\Omega$, calculate the loaded output voltage? (6 marks)

- d) With 21 V applied, if $R_1 = 5\text{ ohms}$, $R_2 = 35\text{ ohms}$, and $R_3 = 14\text{ ohms}$, what is the current of R_2 if R_1 is series connected with parallel circuit R_2 and R_3 ? (6 marks)

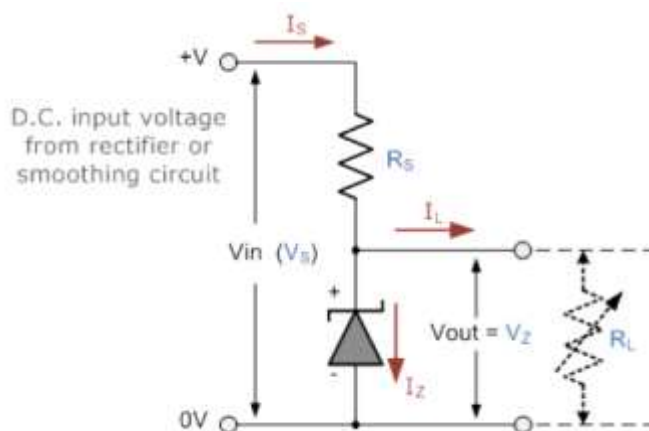
- e) Explain why an ordinary junction transistor is called bipolar? (2 marks)
- f) Calculate the total resistance of a circuit when R_1 ($7\text{ k}\Omega$) is in series with a parallel combination of R_2 ($20\text{ k}\Omega$), R_3 ($36\text{ k}\Omega$), and R_4 ($45\text{ k}\Omega$)? (4 marks)
- g) Discuss the input and output characteristics of a CE Junction Transistor? (4 marks)

QUESTION TWO (20 MARKS)

- a) Define the following;
 i) fermi level
 ii) hole in a semiconductor
 iii) doping
 iv) p-n junction (8 marks)
- b) Differentiate between valence band and conduction band (4 marks)
- c) Explain the effect of temperature on extrinsic semiconductor (4 marks)
- d) Explain the term doping and its need (4 marks)

QUESTIONS THREE (20 MARKS)

- a) Define zener diode? (2 marks)
- b) Mention three application of zener diode (3 marks)
- c) Briefly explain why zener diode is used as a voltage regulator (4 marks)



A 5.0V stabilized power supply is required to be produced from a 12V DC power supply input source. The maximum power rating P_Z of the zener diode is 2W. Using the zener regulator circuit above calculate.

- i) The maximum current flowing through the zener diode. (3 marks)
- ii) The minimum value of the series resistor, R_S (4 marks)
- iii) The load current I_L if a load resistor of $1k\Omega$ is connected across the zener diode. (3 marks)
- iv) The zener current I_Z at full load. (2 marks)

QUESTION FOUR (20 MARKS)

- a) State three application of a tunnel diode (3 marks)
- b) Discuss the need for biasing a transistor (4 marks)
- c) A transistor has a β_{DC} of 250 and a base current, I_B , of $20 \mu A$. Calculate the collector current, I_C (4 marks)
- d) Explain how BJT can be used as an amplifier. (5 marks)
- e) Determine the source-to-drain voltage required to bias a p-channel depletion-mode MOSFET in the saturation region.
Consider a depletion-mode p-channel MOSFET for which $K_p = 0.2mA/V^2$, $V_{TP} = +0.50 V$ and $i_D = 0.50 mA$. (4 marks)

QUESTION FIVE (20 MARKS)

- a) With the aid of a well labeled diagram, explain the following Bipolar transistor configurations.
 - i) Common Base Configuration (4 marks)
 - ii) Common Emitter Configuration (4 marks)
 - iii) Common Collector configuration (4 marks)
- b) Briefly discuss the three regions of Operation in MOSFET (6 marks)
- c) Give two disadvantages of using Metal Oxide Semiconductor Field Effect Transistor (MOSFET) (2 marks)